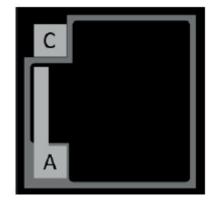
T1678P





Silicon PIN Photodiode



FEATURES

- Package type: chip
- Package form: single chip
- Dimensions (L x W x H in mm): 0.72 x 0.72 x 0.2
- Radiant sensitive area (in mm²): 0.34
- Peak sensitivity wavelength: 570 nm
- High photo sensitivity
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 60^{\circ}$
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

Ambient light sensor

DESCRIPTION

T1678P ambient light chip is an epitaxial photodiode with ambient light spectral characteristic. Anode and cathode contact are bond pads on top of the chip.

GENERAL INFORMATION

The datasheet is based on Vishay optoelectronics sample testing under certain predetermined and assumed conditions, and is provided for illustration purpose only. Customers are encouraged to perform testing in actual proposed packaged and used conditions. Vishay optoelectronics die products are tested using Vishay optoelectronics based quality assurance procedures and are manufactured using Vishay optoelectronics established processes. Estimates such as those described and set forth in this datasheet for semiconductor die will vary depending on a number of packaging, handling, use, and other factors. Therefore sold die may not perform on an equivalent basis to standard package products.

PRODUCT SUMMARY				
COMPONENT	I _{ra} (nA)	φ (deg)	λ _{0.5} (nm)	
T1678P	15	± 60	440 to 700	

Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
T1678P-SD-F	Wafer sawn on foil with disco frame	MOQ: 58 000 pcs	Chip		

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	16	V	
Junction temperature		Tj	100	°C	
Operating temperature range		T _{amb}	-40 to +100	°C	
Storage temperature range		T _{stg1}	-40 to +100	°C	
Storage temperature range on foil		T _{stg2}	-40 to +50	°C	

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BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION SYMBOL N		MIN.	TYP.	MAX.	UNIT
Breakdown voltage	I _R = 100 μA, E = 0	V _(BR)	16			V
Reverse dark current	V _R = 10 V, E = 0 I _{ro}		0.1	2	nA	
	$V_{R} = 0 V, f = 1 MHz, E = 0$	CD		72		pF
Diode capacitance	$V_R = 3 V, f = 1 MHz, E = 0$	CD		35		pF
	E_e = 10 μ W/cm ² , λ = 530 nm, V _R = 5 V	I _{ra}		15		nA
Reverse light current	$E_V = 100 \text{ lux}$, white LED 4300 K, $V_R = 5 \text{ V}$	I _{ra}		43		nA
	$E_V = 100 \text{ lux}, \text{CIE}$ illumination A, $V_R = 5 \text{ V}$	I _{ra}		87		nA
Angle of half sensitivity		φ		± 60		deg
Wavelength of peak sensitivity		λρ		570		nm
Range of spectral bandwidth		λ _{0.5}		440 to 700		nm
Rise time	$V_{B} = 5 V, R_{I} = 50 k\Omega, \lambda = 515 nm$	t _r		100		ns
Fall time	$v_{\rm R} = 5 v, n_{\rm L} = 50 \text{ ksz}, \lambda = 515 \text{ mm}$	t _f		100		ns
Rise time	$V_{\rm r} = 5 V_{\rm r} B_{\rm r} = 1000 k_{\rm r} h_{\rm r} = 515 \rm nm$	t _r		415		ns
Fall time	$V_R = 5 \text{ V}, \text{ R}_L = 1000 \text{ k}\Omega, \lambda = 515 \text{ nm}$	t _f		415		ns

Note

• The measurements are based on samples of die which are mounted on a TO18-header without resin coating

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

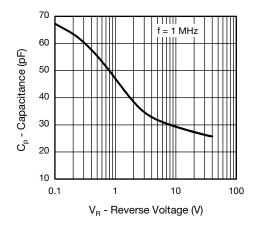
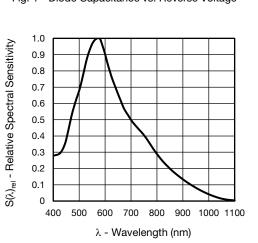
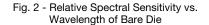


Fig. 1 - Diode Capacitance vs. Reverse Voltage





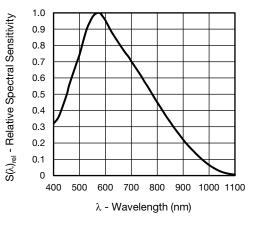


Fig. 3 - Relative Spectral Sensitivity vs. Wavelength of Epoxy Coated Die

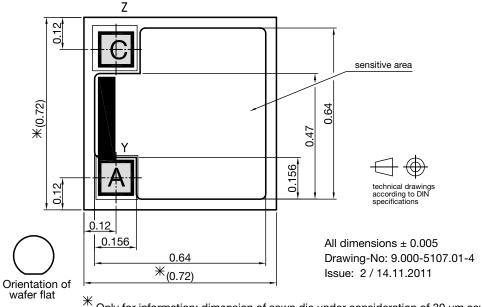
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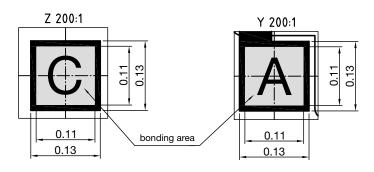


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DIMENSIONS in millimeters



 $^{\bigstar}$ Only for information: dimension of sawn die under consideration of 30 μm saw kerf



A: Anode C: Cathode Opt. sensitive area: 0.34 mm² Thickness: 200 $\mu m \pm 15 \ \mu m$

Bonding area: A: 110 µm x 110 µm C: 110 µm x 110 µm Bonding restricted to this area in order to avoid damage of adjacent structures

MECHANICAL DIMENSIONS					
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Length of chip edge (x-direction)	L _x		0.72		mm
Length of chip edge (y-direction)	Ly		0.72		mm
Sensitive area	As		0.34		mm ²
Wafer diameter	D		100		mm
Die height	Н	0.185	0.2	0.215	mm
Bond pad anode			0.11 x 0.11		mm ²
Bond pad cathode			0.11 x 0.11		mm ²



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ADDITIONAL INFORMATION				
Frontside metallization, anode, cathode AlSi				
Backside	Electrically isolated			
Dicing	Sawing			
Die bonding technology	Epoxy bonding			

Note

All chips are checked in accordance with the Vishay Semiconductor, specification of visual inspection FVOV6870.

The visual inspection shall be made in accordance with the "specification of visual inspection as referenced". The visual inspection of chip backside is performed with stereo microscope with incident light and 40x to 80x magnification.

The quality inspection (final visual inspection) is performed by production. An additional visual inspection step as special release procedure by QM is not installed.

HANDLING AND STORAGE CONDITIONS

- The hermetically sealed shipment lots shall be opened in temperature and moisture controlled cleanroom environment only. It is mandatory to follow the rules for disposition of material that can be hazardous for humans and environment.
- Product must be handled only at ESD safe workstations. Standard ESD precautions and safe work environments are as defined in MIL-HDBK-263.
- Singulated die are not to be handled with tweezers. A vacuum wand with non metallic ESD protected tip should be used.

PACKING

Chips are fixed on adhesive foil. Upon request the foils can be mounted on plastic frame or disco frame. For shipment, the wafers are arranged to stacks and hermetically sealed in plastic bags to ensure protection against environmental influence (humidity and contamination).

Use for recycling reliable operators only. We can help getting in touch with your nearest sales office. By agreement we will take back packing material, if it is sorted. You will have to bear the costs of transport. We will invoice you for any costs incurred for packing material that is returned unsorted or which we are not obliged to accept.



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